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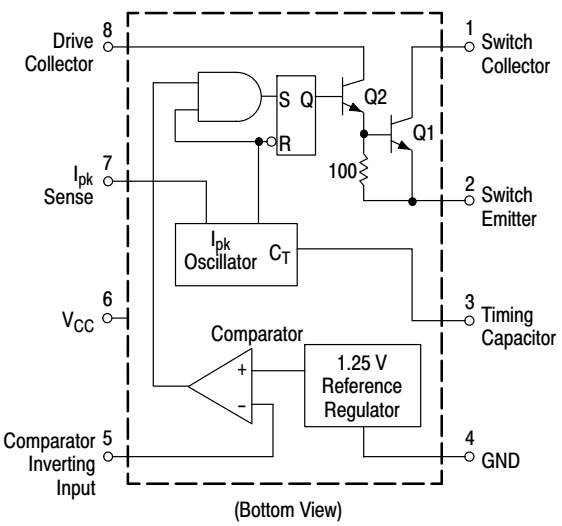
MC34063A, MC33063A, SC34063A, SC33063A, NCV33063A

1.5 A, Step-Up/Down/ Inverting Switching Regulators

The MC34063A Series is a monolithic control circuit containing the primary functions required for DC−to−DC converters. These devices consist of an internal temperature compensated reference, comparator, controlled duty cycle oscillator with an active current limit circuit, driver and high current output switch. This series was specifically designed to be incorporated in Step−Down and Step−Up and Voltage−Inverting applications with a minimum number of external components. Refer to Application Notes AN920A/D and AN954/D for additional design information.

Features

- Operation from 3.0 V to 40 V Input
- Low Standby Current
- Current Limiting
- Output Switch Current to 1.5 A
- Output Voltage Adjustable
- Frequency Operation to 100 kHz
- Precision 2% Reference
- Pb−Free Packages are Available



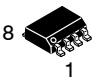
This device contains 79 active transistors.

Figure 1. Representative Schematic Diagram

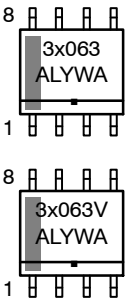
ON Semiconductor®

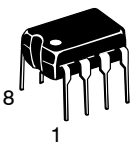
http://onsemi.com

MARKING DIAGRAMS

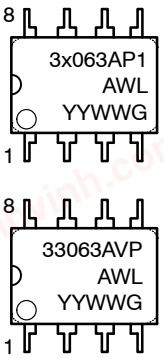


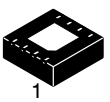
SOIC−8
D SUFFIX
CASE 751



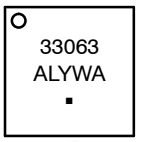


PDIP−8
P, P1 SUFFIX
CASE 626





DFN8
CASE 488AF



x	= 3 or 4
A	= Assembly Location
L, WL	= Wafer Lot
Y, YY	= Year
W, WW	= Work Week
G or ▪	= Pb−Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 12 of this data sheet.

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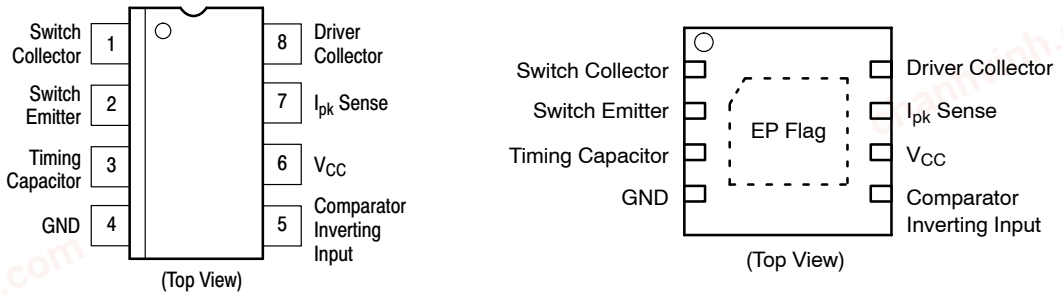


Figure 2. Pin Connections

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Supply Voltage	V_{CC}	40	Vdc
Comparator Input Voltage Range	V_{IR}	−0.3 to +40	Vdc
Switch Collector Voltage	$V_{C(switch)}$	40	Vdc
Switch Emitter Voltage ($V_{Pin\ 1}$ = 40 V)	$V_{E(switch)}$	40	Vdc
Switch Collector to Emitter Voltage	$V_{CE(switch)}$	40	Vdc
Driver Collector Voltage	$V_{C(driver)}$	40	Vdc
Driver Collector Current (Note 1)	$I_{C(driver)}$	100	mA
Switch Current	I_{SW}	1.5	A
Power Dissipation and Thermal Characteristics			
Plastic Package, P, P1 Suffix			
T_A = 25°C	P_D	1.25	W
Thermal Resistance	$R_{\theta JA}$	115	°C/W
SOIC Package, D Suffix			
T_A = 25°C	P_D	625	mW
Thermal Resistance	$R_{\theta JA}$	160	°C/W
DFN Package			
T_A = 25°C	P_D	1.25	mW
Thermal Resistance	$R_{\theta JA}$	80	°C/W
Operating Junction Temperature	T_J	+150	°C
Operating Ambient Temperature Range	T_A		°C
MC34063A, SC34063A		0 to +70	
MC33063AV, NCV33063A		−40 to +125	
MC33063A, SC33063A		−40 to +85	
Storage Temperature Range	T_{stg}	−65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Maximum package power dissipation limits must be observed.
2. This device series contains ESD protection and exceeds the following tests: Human Body Model 4000 V per MIL−STD−883, Method 3015. Machine Model Method 400 V.
3. NCV prefix is for automotive and other applications requiring site and change control.

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ELECTRICAL CHARACTERISTICS (V_{CC} = 5.0 V, T_A = T_{low} to T_{high} [Note 4], unless otherwise specified.)

Characteristics	Symbol	Min	Typ	Max	Unit
OSCILLATOR					
Frequency ($V_{Pin\ 5}$ = 0 V, C_T = 1.0 nF, T_A = 25°C)	f_{osc}	24	33	42	kHz
Charge Current (V_{CC} = 5.0 V to 40 V, T_A = 25°C)	I_{chg}	24	35	42	μA
Discharge Current (V_{CC} = 5.0 V to 40 V, T_A = 25°C)	I_{dischg}	140	220	260	μA
Discharge to Charge Current Ratio (Pin 7 to V_{CC}, T_A = 25°C)	I_{dischg}/I_{chg}	5.2	6.5	7.5	–
Current Limit Sense Voltage (I_{chg} = I_{dischg}, T_A = 25°C)	$V_{ipk(sense)}$	250	300	350	mV
OUTPUT SWITCH (Note 5)					
Saturation Voltage, Darlington Connection (I_{SW} = 1.0 A, Pins 1, 8 connected)	$V_{CE(sat)}$	–	1.0	1.3	V
Saturation Voltage (Note 6) (I_{SW} = 1.0 A, $R_{Pin\ 8}$ = 82 Ω to V_{CC}, Forced β ≃ 20)	$V_{CE(sat)}$	–	0.45	0.7	V
DC Current Gain (I_{SW} = 1.0 A, V_{CE} = 5.0 V, T_A = 25°C)	h_{FE}	50	75	–	–
Collector Off−State Current (V_{CE} = 40 V)	$I_{C(off)}$	–	0.01	100	μA
COMPARATOR					
Threshold Voltage T_A = 25°C T_A = T_{low} to T_{high}	V_{th}	 1.225 1.21	 1.25 –	 1.275 1.29	V
Threshold Voltage Line Regulation (V_{CC} = 3.0 V to 40 V) MC33063, MC34063 MC33063V, NCV33063	Reg_{line}	 – –	 1.4 1.4	 5.0 6.0	mV
Input Bias Current (V_{in} = 0 V)	I_{IB}	–	−20	−400	nA
TOTAL DEVICE					
Supply Current (V_{CC} = 5.0 V to 40 V, C_T = 1.0 nF, Pin 7 = V_{CC}, $V_{Pin\ 5}$ > V_{th}, Pin 2 = GND, remaining pins open)	I_{CC}	–	–	4.0	mA

4. T_{low} = 0°C for MC34063, SC34063; −40°C for MC33063, SC33063, MC33063V, NCV33063
   T_{high} = +70°C for MC34063, SC34063; +85°C for MC33063, SC33063; +125°C for MC33063V, NCV33063
5. Low duty cycle pulse techniques are used during test to maintain junction temperature as close to ambient temperature as possible.
6. If the output switch is driven into hard saturation (non−Darlington configuration) at low switch currents (≤ 300 mA) and high driver currents (≥ 30 mA), it may take up to 2.0 μs for it to come out of saturation. This condition will shorten the off time at frequencies ≥ 30 kHz, and is magnified at high temperatures. This condition does not occur with a Darlington configuration, since the output switch cannot saturate. If a non−Darlington configuration is used, the following output drive condition is recommended:

   Forced β of output switch : $\frac{I_C \text{ output}}{I_C \text{ driver} - 7.0\ mA^*} \geq 10$

*The 100 Ω resistor in the emitter of the driver device requires about 7.0 mA before the output switch conducts.

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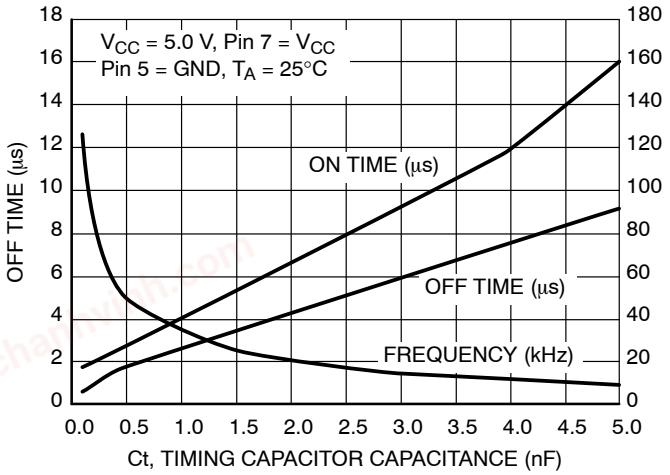


Figure 3. Oscillator Frequency

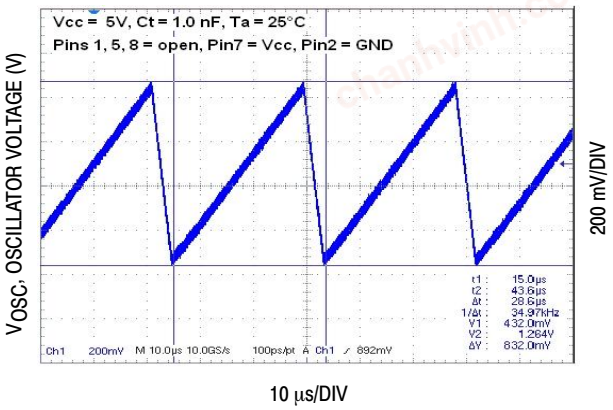


Figure 4. Timing Capacitor Waveform

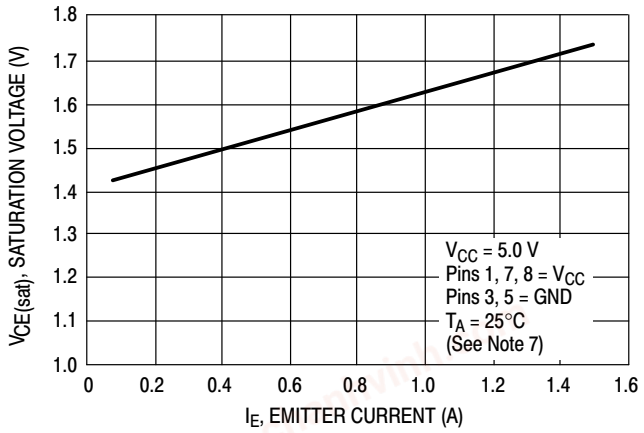


Figure 5. Emitter Follower Configuration Output Saturation Voltage versus Emitter Current

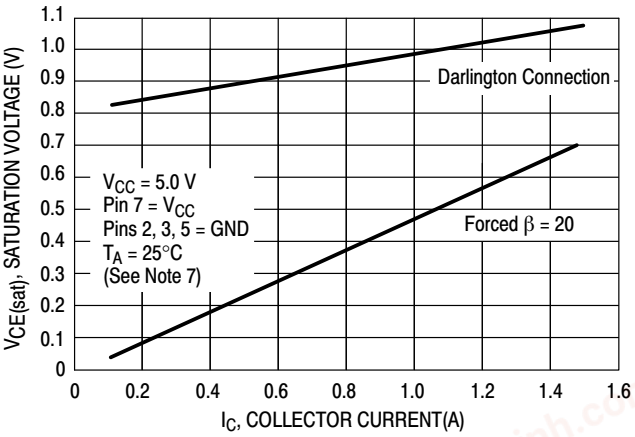


Figure 6. Common Emitter Configuration Output Switch Saturation Voltage versus Collector Current

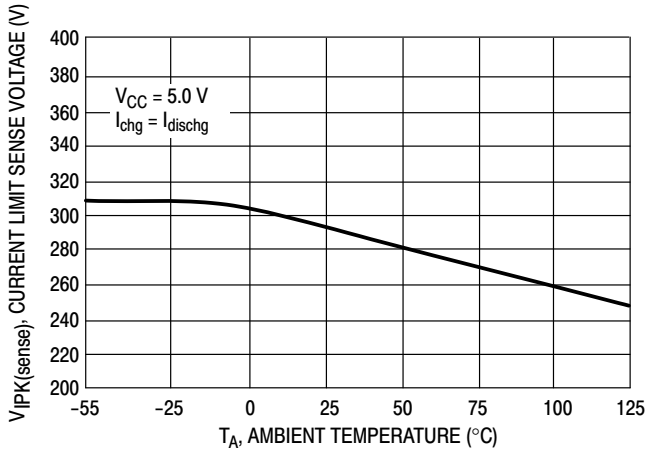


Figure 7. Current Limit Sense Voltage versus Temperature

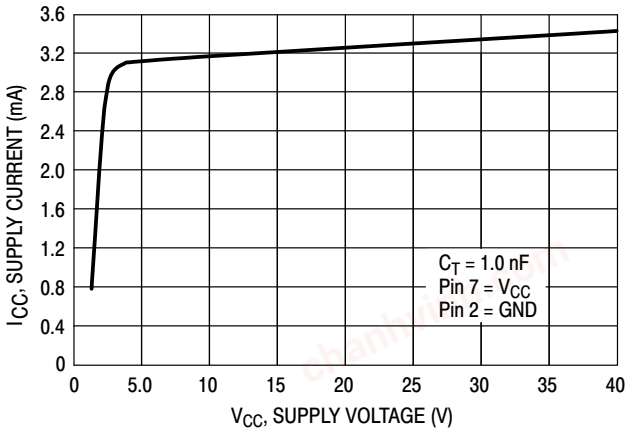
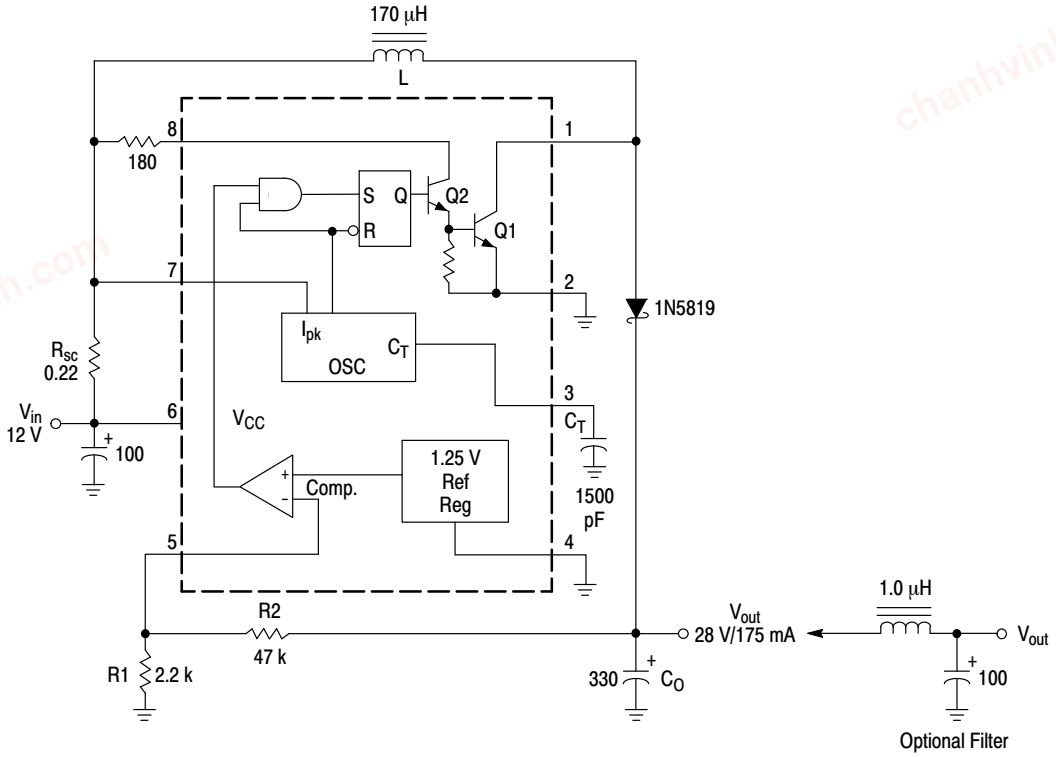


Figure 8. Standby Supply Current versus Supply Voltage

7. Low duty cycle pulse techniques are used during test to maintain junction temperature as close to ambient temperature as possible.

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Test	Conditions	Results
Line Regulation	V_{in} = 8.0 V to 16 V, I_O = 175 mA	30 mV = ±0.05%
Load Regulation	V_{in} = 12 V, I_O = 75 mA to 175 mA	10 mV = ±0.017%
Output Ripple	V_{in} = 12 V, I_O = 175 mA	400 mVpp
Efficiency	V_{in} = 12 V, I_O = 175 mA	87.7%
Output Ripple With Optional Filter	V_{in} = 12 V, I_O = 175 mA	40 mVpp

Figure 9. Step−Up Converter

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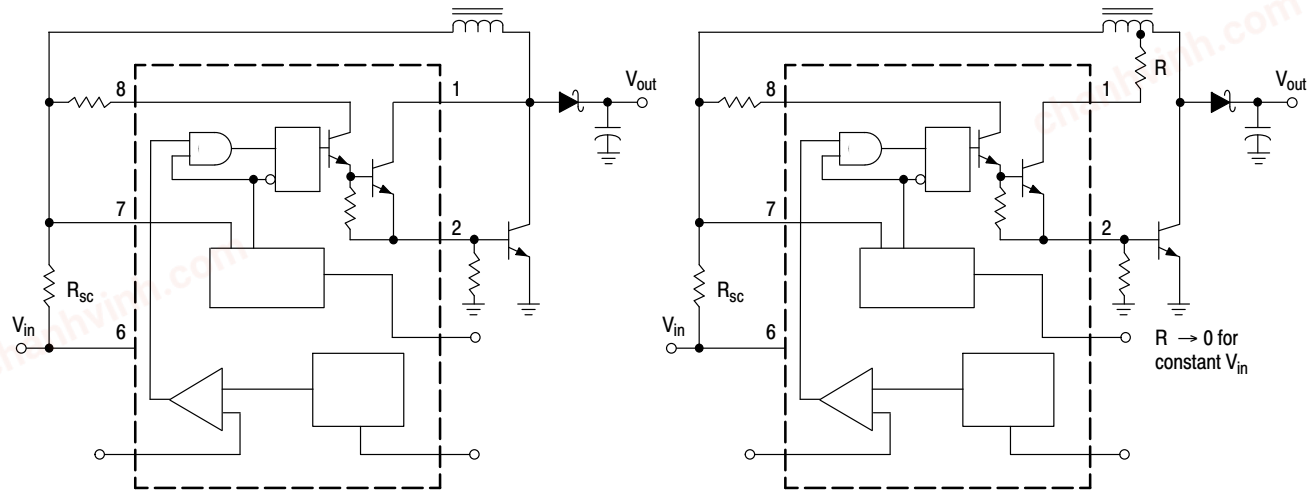


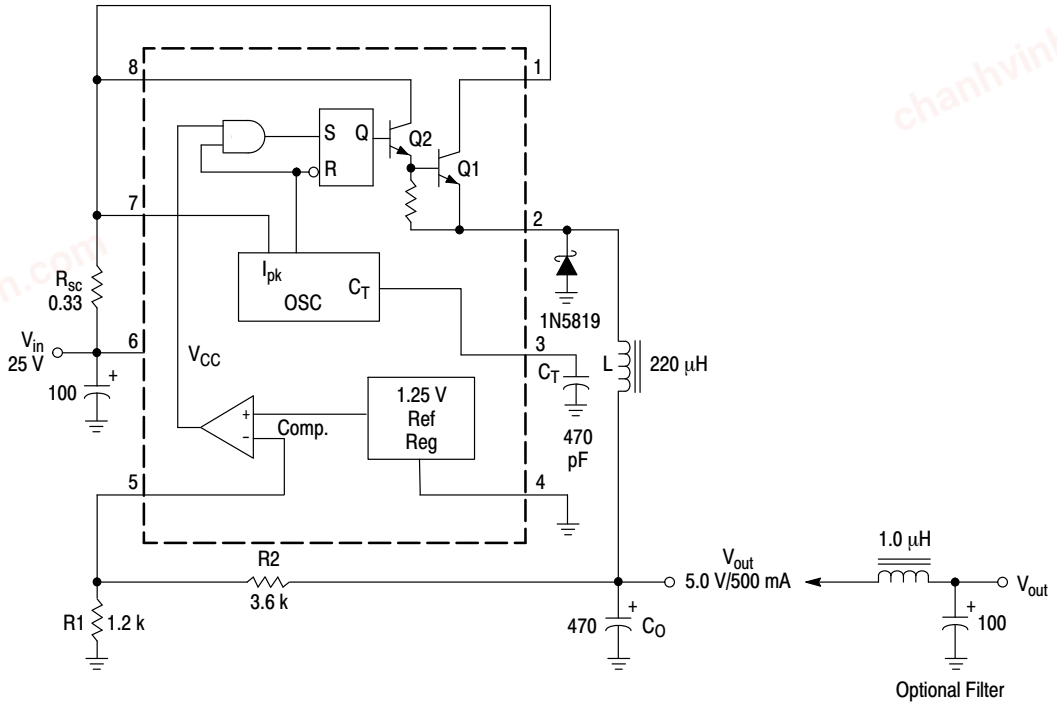
Figure 10. External Current Boost Connections for I_C Peak Greater than 1.5 A

9a. External NPN Switch

9b. External NPN Saturated Switch
(See Note 8)

8. If the output switch is driven into hard saturation (non−Darlington configuration) at low switch currents (≤ 300 mA) and high driver currents (≥ 30 mA), it may take up to 2.0 μs to come out of saturation. This condition will shorten the off time at frequencies ≥ 30 kHz, and is magnified at high temperatures. This condition does not occur with a Darlington configuration, since the output switch cannot saturate. If a non−Darlington configuration is used, the following output drive condition is recommended.

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Test	Conditions	Results
Line Regulation	V_{in} = 15 V to 25 V, I_O = 500 mA	12 mV = ±0.12%
Load Regulation	V_{in} = 25 V, I_O = 50 mA to 500 mA	3.0 mV = ±0.03%
Output Ripple	V_{in} = 25 V, I_O = 500 mA	120 mVpp
Short Circuit Current	V_{in} = 25 V, R_L = 0.1 Ω	1.1 A
Efficiency	V_{in} = 25 V, I_O = 500 mA	83.7%
Output Ripple With Optional Filter	V_{in} = 25 V, I_O = 500 mA	40 mVpp

Figure 11. Step−Down Converter

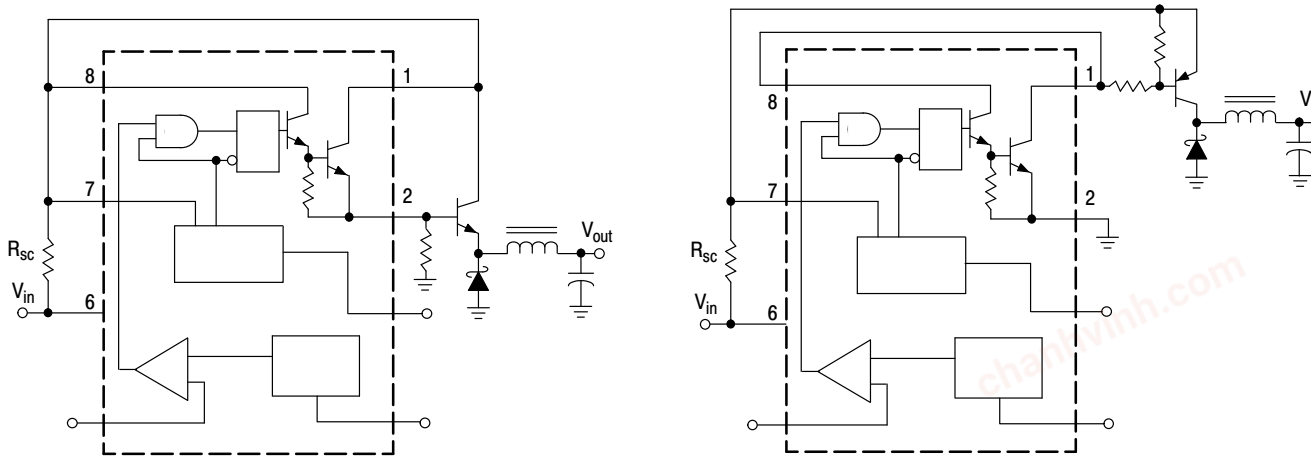
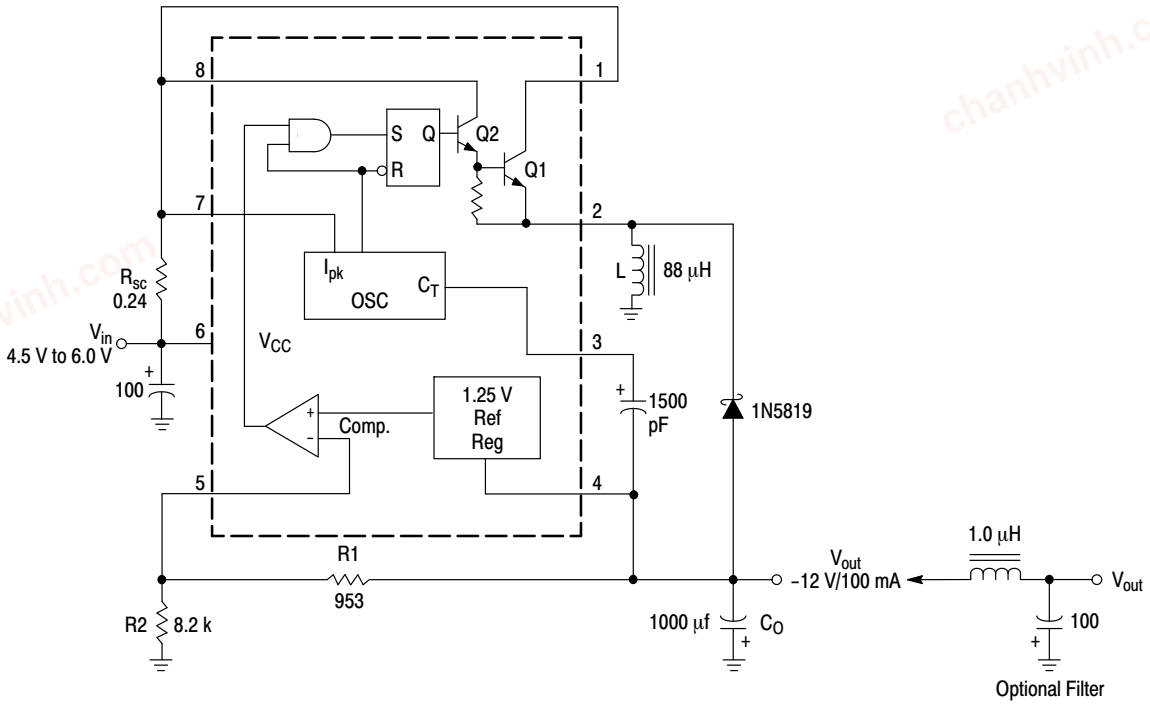


Figure 12. External Current Boost Connections for I_C Peak Greater than 1.5 A

11a. External NPN Switch **11b. External PNP Saturated Switch**

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Test	Conditions	Results
Line Regulation	V_{in} = 4.5 V to 6.0 V, I_O = 100 mA	3.0 mV = ±0.012%
Load Regulation	V_{in} = 5.0 V, I_O = 10 mA to 100 mA	0.022 V = ±0.09%
Output Ripple	V_{in} = 5.0 V, I_O = 100 mA	500 mVpp
Short Circuit Current	V_{in} = 5.0 V, R_L = 0.1 Ω	910 mA
Efficiency	V_{in} = 5.0 V, I_O = 100 mA	62.2%
Output Ripple With Optional Filter	V_{in} = 5.0 V, I_O = 100 mA	70 mVpp

Figure 13. Voltage Inverting Converter

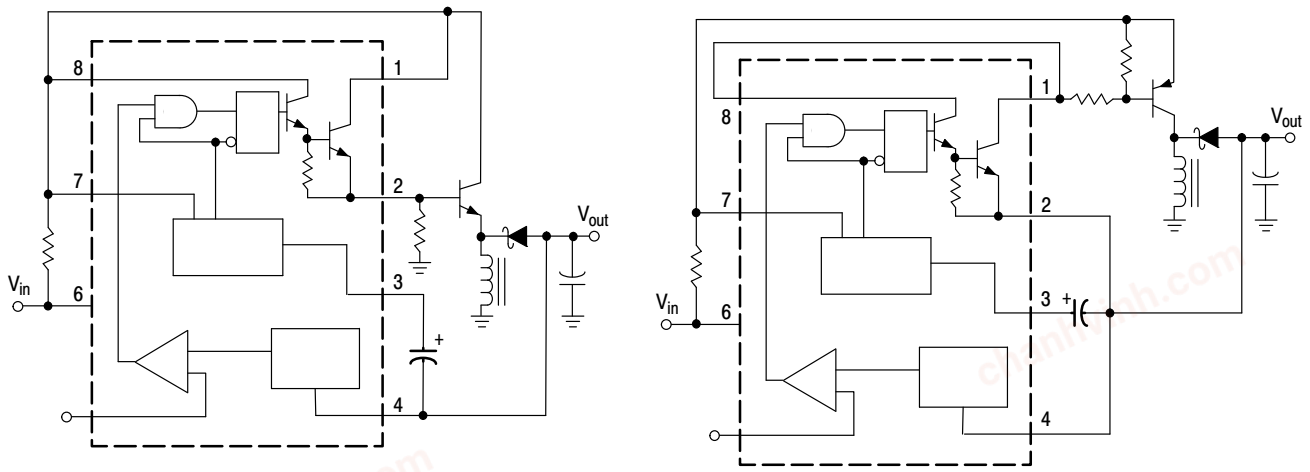
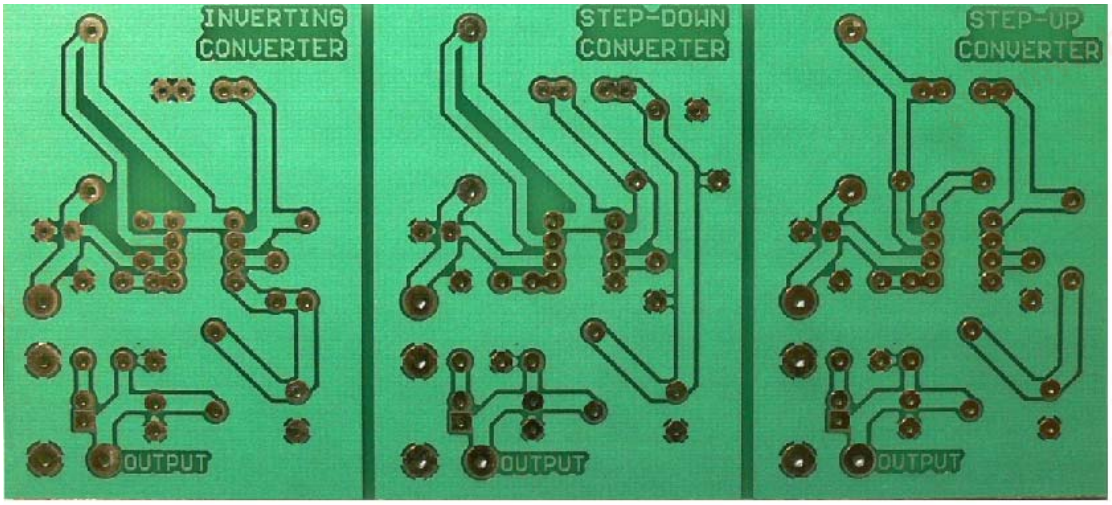


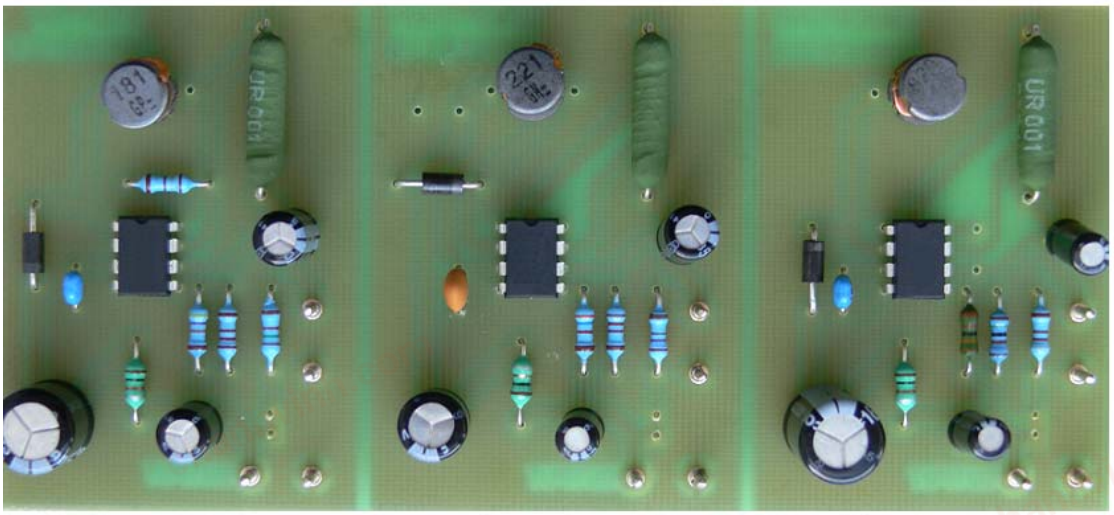
Figure 14. External Current Boost Connections for I_C Peak Greater than 1.5 A

13a. External NPN Switch **13b. External PNP Saturated Switch**

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(Bottom Side)



(Top View, Component Side)

Figure 15. Printed Circuit Board and Component Layout
(Circuits of Figures 9, 11, 13)

INDUCTOR DATA

Converter	Inductance (μH)	Turns/Wire
Step−Up	170	38 Turns of #22 AWG
Step−Down	220	48 Turns of #22 AWG
Voltage−Inverting	88	28 Turns of #22 AWG

All inductors are wound on Magnetics Inc. 55117 toroidal core.

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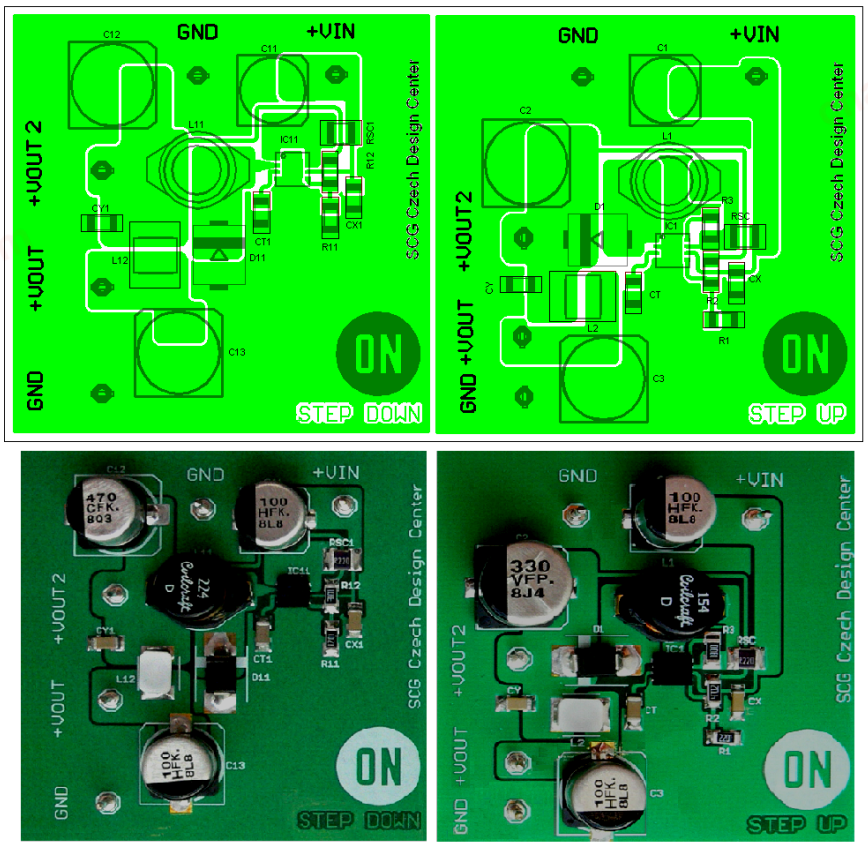


Figure 16. Printed Circuit Board for DFN Device

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Calculation	Step−Up	Step−Down	Voltage−Inverting
t_{on}/t_{off}	$\frac{V_{out} + V_F - V_{in(min)}}{V_{in(min)} - V_{sat}}$	$\frac{V_{out} + V_F}{V_{in(min)} - V_{sat} - V_{out}}$	$\frac{\lvert V_{out}\rvert + V_F}{V_{in} - V_{sat}}$
$(t_{on} + t_{off})$	$\frac{1}{f}$	$\frac{1}{f}$	$\frac{1}{f}$
t_{off}	$\frac{t_{on} + t_{off}}{\frac{t_{on}}{t_{off}} + 1}$	$\frac{t_{on} + t_{off}}{\frac{t_{on}}{t_{off}} + 1}$	$\frac{t_{on} + t_{off}}{\frac{t_{on}}{t_{off}} + 1}$
t_{on}	$(t_{on} + t_{off}) - t_{off}$	$(t_{on} + t_{off}) - t_{off}$	$(t_{on} + t_{off}) - t_{off}$
C_T	$4.0 \times 10^{-5}\, t_{on}$	$4.0 \times 10^{-5}\, t_{on}$	$4.0 \times 10^{-5}\, t_{on}$
$I_{pk(switch)}$	$2I_{out(max)}\left(\frac{t_{on}}{t_{off}} + 1\right)$	$2I_{out(max)}$	$2I_{out(max)}\left(\frac{t_{on}}{t_{off}} + 1\right)$
R_{sc}	$0.3/I_{pk(switch)}$	$0.3/I_{pk(switch)}$	$0.3/I_{pk(switch)}$
$L_{(min)}$	$\left(\frac{(V_{in(min)} - V_{sat})}{I_{pk(switch)}}\right) t_{on(max)}$	$\left(\frac{(V_{in(min)} - V_{sat} - V_{out})}{I_{pk(switch)}}\right) t_{on(max)}$	$\left(\frac{(V_{in(min)} - V_{sat})}{I_{pk(switch)}}\right) t_{on(max)}$
C_O	$9\,\frac{I_{out} t_{on}}{V_{ripple(pp)}}$	$\frac{I_{pk(switch)}(t_{on} + t_{off})}{8V_{ripple(pp)}}$	$9\,\frac{I_{out} t_{on}}{V_{ripple(pp)}}$

V_{sat} = Saturation voltage of the output switch.
V_F = Forward voltage drop of the output rectifier.

The following power supply characteristics must be chosen:

V_{in} − Nominal input voltage.
V_{out} − Desired output voltage, $\lvert V_{out}\rvert = 1.25\left(1 + \frac{R2}{R1}\right)$
I_{out} − Desired output current.
f_{min} − Minimum desired output switching frequency at the selected values of V_{in} and I_O.
$V_{ripple(pp)}$ − Desired peak−to−peak output ripple voltage. In practice, the calculated capacitor value will need to be increased due to its equivalent series resistance and board layout. The ripple voltage should be kept to a low value since it will directly affect the line and load regulation.

NOTE: For further information refer to Application Note AN920A/D and AN954/D.

Figure 17. Design Formula Table

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ORDERING INFORMATION

Device	Package	Shipping†
MC33063AD	SOIC−8	98 Units / Rail
MC33063ADG	SOIC−8 (Pb−Free)	98 Units / Rail
MC33063ADR2	SOIC−8	2500 Units / Tape & Reel
MC33063ADR2G	SOIC−8 (Pb−Free)	2500 Units / Tape & Reel
SC33063ADR2G	SOIC−8 (Pb−Free)	2500 Units / Tape & Reel
MC33063AP1	PDIP−8	50 Units / Rail
MC33063AP1G	PDIP−8 (Pb−Free)	50 Units / Rail
MC33063AVD	SOIC−8	98 Units / Rail
MC33063AVDG	SOIC−8 (Pb−Free)	98 Units / Rail
MC33063AVDR2	SOIC−8	2500 Units / Tape & Reel
MC33063AVDR2G	SOIC−8 (Pb−Free)	
NCV33063AVDR2*	SOIC−8	
NCV33063AVDR2G*	SOIC−8 (Pb−Free)	
MC33063AVP	PDIP−8	50 Units / Rail
MC33063AVPG	PDIP−8 (Pb−Free)	50 Units / Rail
MC34063AD	SOIC−8	98 Units / Rail
MC34063ADG	SOIC−8 (Pb−Free)	98 Units / Rail
MC34063ADR2	SOIC−8	2500 Units / Tape & Reel
MC34063ADR2G	SOIC−8 (Pb−Free)	2500 Units / Tape & Reel
SC34063ADR2G	SOIC−8 (Pb−Free)	2500 Units / Tape & Reel
MC34063AP1	PDIP−8	50 Units / Rail
MC34063AP1G	PDIP−8 (Pb−Free)	50 Units / Rail
SC34063AP1G	PDIP−8 (Pb−Free)	50 Units / Rail
MC33063MNTXG	DFN8 (Pb−Free)	4000 Units / Tape & Reel

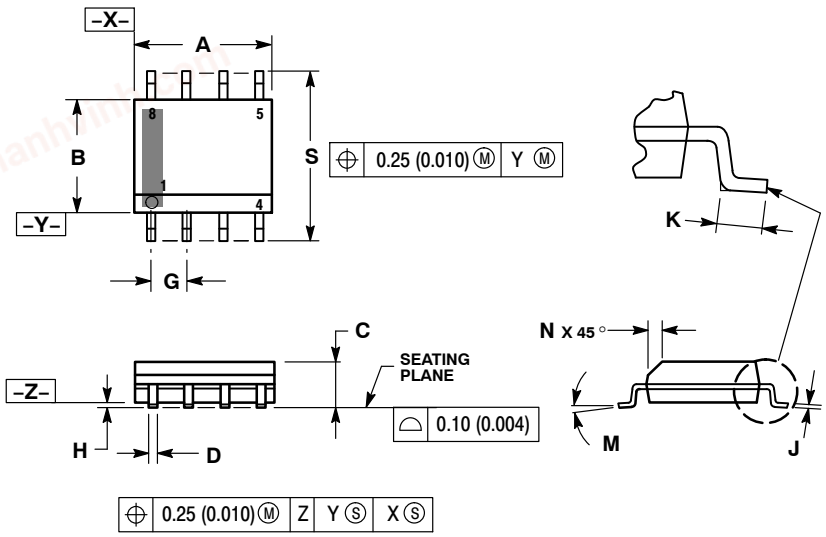
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

*NCV33063A: T_{low} = −40°C, T_{high} = +125°C. Guaranteed by design. NCV prefix is for automotive and other applications requiring site and change control.

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PACKAGE DIMENSIONS

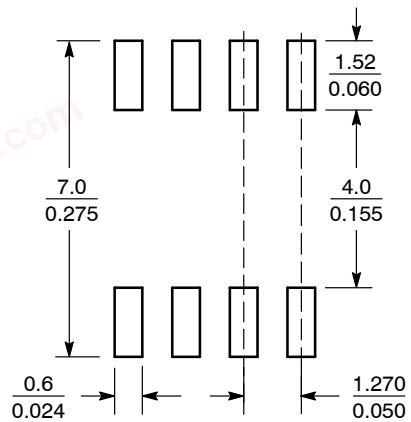
SOIC−8 NB
CASE 751−07
ISSUE AJ



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751−01 THRU 751−06 ARE OBSOLETE. NEW STANDARD IS 751−07.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0 °	8 °	0 °	8 °
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

SOLDERING FOOTPRINT*



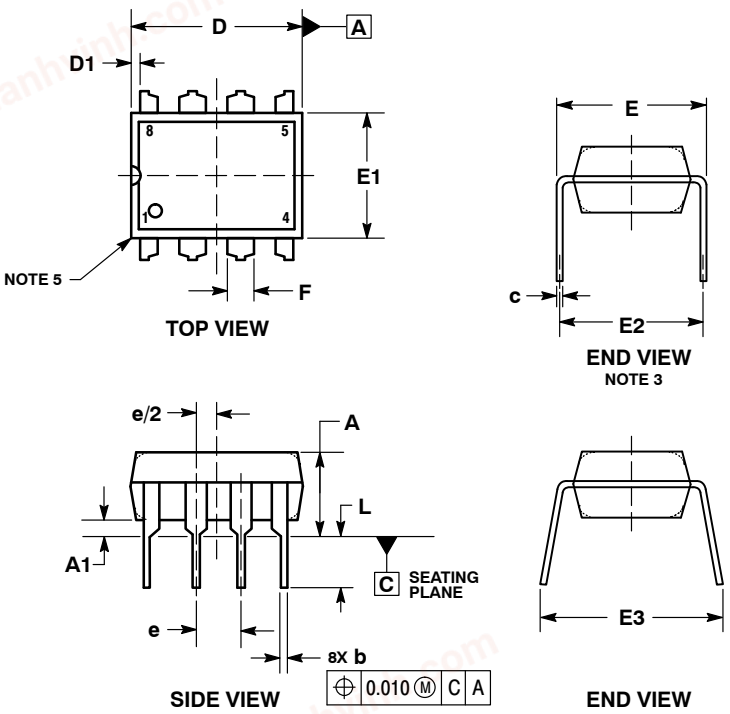
SCALE 6:1 (mm / inches)

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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PACKAGE DIMENSIONS

PDIP−8
P, P1 SUFFIX
CASE 626−05
ISSUE M



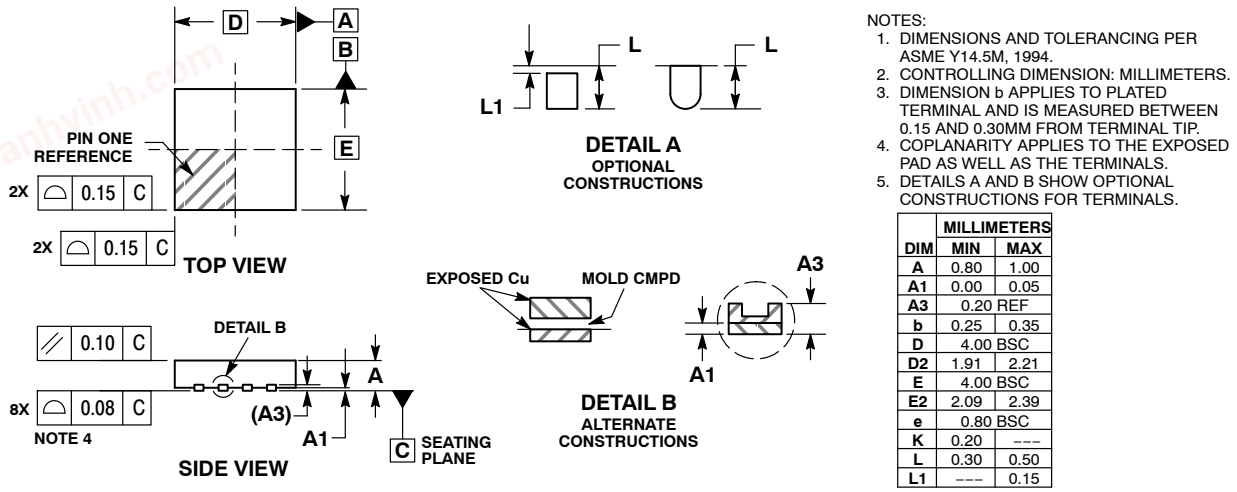
NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. DIMENSION E IS MEASURED WITH THE LEADS RE-STRAINED PARALLEL AT WIDTH E2.
4. DIMENSION E1 DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

	INCHES			MILLIMETERS		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
A	----	----	0.210	----	----	5.33
A1	0.015	----	----	0.38	----	----
b	0.014	0.018	0.022	0.35	0.46	0.56
C	0.008	0.010	0.014	0.20	0.25	0.36
D	0.355	0.365	0.400	9.02	9.27	10.02
D1	0.005	----	----	0.13	----	----
E	0.300	0.310	0.325	7.62	7.87	8.26
E1	0.240	0.250	0.280	6.10	6.35	7.11
E2	0.300 BSC			7.62 BSC		
E3	----	----	0.430	----	----	10.92
e	0.100 BSC			2.54 BSC		
L	0.115	0.130	0.150	2.92	3.30	3.81

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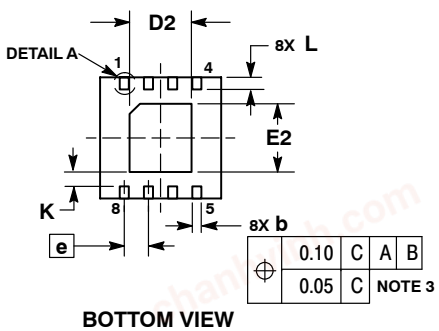
PACKAGE DIMENSIONS

DFN8, 4x4
CASE 488AF−01
ISSUE C

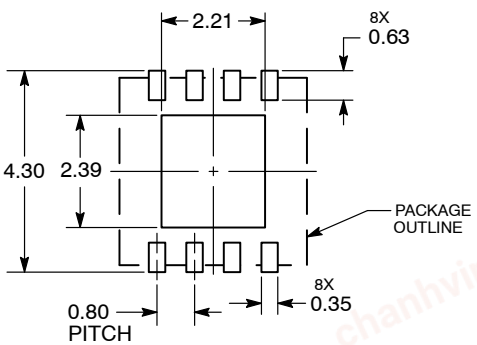


NOTES:
1. DIMENSIONS AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30MM FROM TERMINAL TIP.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
5. DETAILS A AND B SHOW OPTIONAL CONSTRUCTIONS FOR TERMINALS.

	MILLIMETERS	
DIM	MIN	MAX
A	0.80	1.00
A1	0.00	0.05
A3	0.20 REF	
b	0.25	0.35
D	4.00 BSC	
D2	1.91	2.21
E	4.00 BSC	
E2	2.09	2.39
e	0.80 BSC	
K	0.20	---
L	0.30	0.50
L1	---	0.15



SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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